

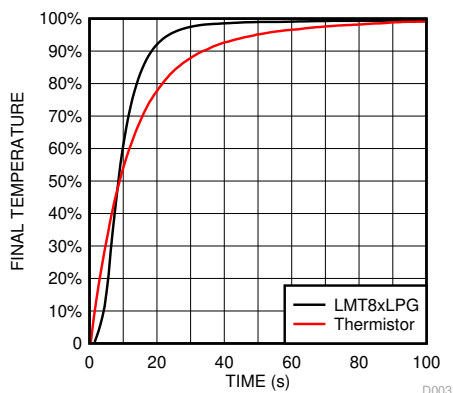
LMT86-Q1 2.2-V、SC70、 アナログ温度センサ

1 特長

- LMT86-Q1-Q1 は車載用アプリケーション向けに AEC-Q100 認定済み:
 - デバイス温度グレード 0: $-40^{\circ}\text{C} \sim +150^{\circ}\text{C}$
 - デバイス HBM ESD 分類レベル 2
 - デバイス CDM ESD 分類レベル C6
- 機能安全対応
 - 機能安全システムの設計に役立つ資料を利用可能
- 非常に高精度: $\pm 0.4^{\circ}\text{C}$ (標準値)
- 低電圧 2.2V で動作
- 平均センサ・ゲイン: $-10.9\text{mV}/^{\circ}\text{C}$
- 低い静止電流: $5.4\mu\text{A}$
- 広い温度範囲: $-50^{\circ}\text{C} \sim 150^{\circ}\text{C}$
- 出力短絡保護
- 駆動能力 $\pm 50\mu\text{A}$ のプッシュプル出力
- 業界標準の LM20/19 および LM35 温度センサとフットプリント互換
- コスト効率に優れたサーミスタの代替

2 アプリケーション

- 車載用
- インフォテインメントおよびクラスタ
- パワートレイン・システム
- 煙および熱検出器
- ドローン
- 家電製品



* 高速な熱応答 NTC

熱時定数

3 概要

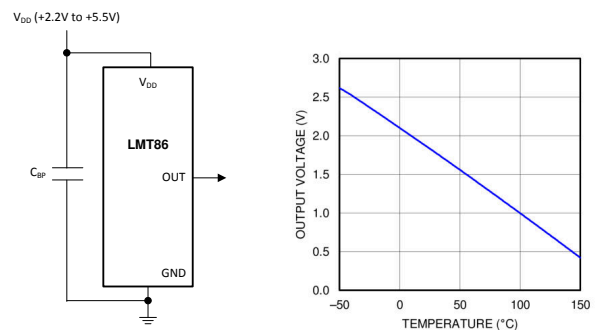
LMT86-Q1 は、高精度の CMOS 温度センサであり、標準精度は $\pm 0.4^{\circ}\text{C}$ (最大値 $\pm 2.7^{\circ}\text{C}$) で、リニアなアナログ出力電圧を備え、この電圧は温度に反比例します。2.2V の電源電圧で動作し、静止電流が $5.4\mu\text{A}$ 、パワーオン時間が 0.7ms で、効果的なパワーサイクリング・アーキテクチャを実現し、ドローンやセンサ・ノードなどバッテリー駆動のアプリケーションで消費電力を最小化できます。LMT86-Q1-Q1 デバイスは、AEC-Q100 グレード 0 認定済みで、較正なしで全動作温度範囲にわたって $\pm 2.7^{\circ}\text{C}$ の最大精度を維持します。このため、LMT86-Q1-Q1 はインフォテインメント、クラスタ、パワートレイン・システムなどの車載アプリケーションに適しています。広い動作範囲にわたる精度や、その他の特長から、LMT86-Q1 はサーミスタの優れた代替となります。

異なる平均センサ・ゲインおよび類似の精度を持つデバイスについては、「類似の代替デバイス」で、LMT8x ファミリの他のデバイスを参照してください。

製品情報(1)

部品番号	パッケージ	本体サイズ (公称)
LMT86-Q1	SOT (5)	2.00mm×1.25mm

- (1) 利用可能なパッケージについては、このデータシートの末尾にある注文情報を参照してください。



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出力電圧と温度との関係



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4 Revision History

資料番号末尾の英字は改訂を表しています。その改訂履歴は英語版に準じています。

Changes from Revision * (October 2017) to Revision A (June 2022)	Page
• 文書全体にわたって表、図、相互参照の採番方法を更新.....	1
• 「特長」セクションに機能安全の箇条書き項目を追加.....	1

5 Device Comparison

表 5-1. Available Device Packages

ORDER NUMBER ⁽¹⁾	PACKAGE	PIN	BODY SIZE (NOM)	MOUNTING TYPE
LMT86DCK	SOT (AKA ⁽²⁾ : SC70, DCK)	5	2.00 mm × 1.25 mm	Surface Mount
LMT86LP	TO-92 (AKA ⁽²⁾ : LP)	3	4.30 mm × 3.50 mm	Through-hole; straight leads
LMT86LPG	TO-92S (AKA ⁽²⁾ : LPG)	3	4.00 mm × 3.15 mm	Through-hole; straight leads
LMT86LPM	TO-92 (AKA ⁽²⁾ : LPM)	3	4.30 mm × 3.50 mm	Through-hole; formed leads
LMT86DCK-Q1	SOT (AKA ⁽²⁾ : SC70, DCK)	5	2.00 mm × 1.25 mm	Surface Mount

- (1) For all available packages and complete order numbers, see the Package Option addendum at the end of the data sheet.
 (2) AKA = Also Known As

表 5-2. Comparable Alternative Devices

DEVICE NAME	AVERAGE OUTPUT SENSOR GAIN	POWER SUPPLY RANGE
LMT84-Q1	-5.5 mV/°C	1.5 V to 5.5 V
LMT85-Q1	-8.2 mV/°C	1.8 V to 5.5 V
LMT86-Q1	-10.9 mV/°C	2.2 V to 5.5 V
LMT87-Q1	-13.6 mV/°C	2.7 V to 5.5 V

6 Pin Configuration and Functions

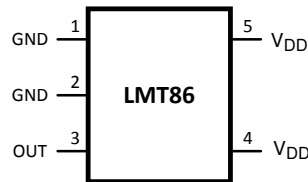
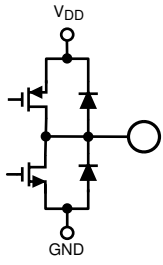


图 6-1. 5-Pin SOT (SC70) DCK Package (TOP VIEW)

表 6-1. Pin Functions

PIN		TYPE	DESCRIPTION	
NAME	SOT (SC70)		EQUIVALENT CIRCUIT	FUNCTION
GND	1, 2 ⁽¹⁾	Ground	N/A	Power Supply Ground
OUT	3	Analog Output		Outputs a voltage that is inversely proportional to temperature
V _{DD}	4, 5	Power	N/A	Positive Supply Voltage

- (1) Direct connection to the back side of the die

7 Specifications

7.1 Absolute Maximum Ratings

See (1) (2)

	MIN	MAX	UNIT
Supply voltage	-0.3	6	V
Voltage at output pin	-0.3	(V _{DD} + 0.5)	V
Output current	-7	7	mA
Input current at any pin (3)	-5	5	mA
Maximum junction temperature (T _{JMAX})		150	°C
Storage temperature, T _{stg}	-65	150	°C

- (1) Stresses beyond those listed under *Absolute Maximum Ratings* may cause permanent damage to the device. These are stress ratings only, which do not imply functional operation of the device at these or any other conditions beyond those indicated under *Recommended Operating Conditions*. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.
- (2) Soldering process must comply with TI's Reflow Temperature Profile specifications. Refer to www.ti.com/packaging. Reflow temperature profiles are different for lead-free and non-lead-free packages.
- (3) When the input voltage (V_I) at any pin exceeds power supplies (V_I < GND or V_I > V), the current at that pin should be limited to 5 mA.

7.2 ESD Ratings

		VALUE	UNIT
LMT86DCK-Q1 in SC70 package			
V _(ESD) Electrostatic discharge	Human-body model (HBM), per AEC Q100-002(1)	±2500	V
	Charged-device model (CDM), per AEC Q100-011	±1000	

- (1) AEC Q100-002 indicates that HBM stressing shall be in accordance with the ANSI/ESDA/JEDEC JS-001 specification.

7.3 Recommended Operating Conditions

	MIN	MAX	UNIT
Specified temperature	T _{MIN} ≤ T _A ≤ T _{MAX}		°C
	-50 ≤ T _A ≤ 150		°C
Supply voltage (V _{DD})	2.2	5.5	V

7.4 Thermal Information

THERMAL METRIC ^{(1) (2)}		LMT86-Q1	UNIT
		DCK (SOT/SC70)	
		5 PINS	
R _{θJA}	Junction-to-ambient thermal resistance (3) (4)	275	°C/W
R _{θJC(top)}	Junction-to-case (top) thermal resistance	84	°C/W
R _{θJB}	Junction-to-board thermal resistance	56	°C/W
ψ _{JT}	Junction-to-top characterization parameter	1.2	°C/W
ψ _{JB}	Junction-to-board characterization parameter	55	°C/W

- (1) For information on self-heating and thermal response time, see section *Mounting and Thermal Conductivity*.
- (2) For more information about traditional and new thermal metrics, see the *IC Package Thermal Metrics* application report.
- (3) The junction to ambient thermal resistance (R_{θJA}) under natural convection is obtained in a simulation on a JEDEC-standard, High-K board as specified in JESD51-7, in an environment described in JESD51-2. Exposed pad packages assume that thermal vias are included in the PCB, per JESD 51-5.
- (4) Changes in output due to self-heating can be computed by multiplying the internal dissipation by the thermal resistance.

7.5 Accuracy Characteristics

These limits do not include DC load regulation. These stated accuracy limits are with reference to the values in 表 8-1.

PARAMETER	CONDITIONS	MIN ⁽¹⁾	TYP ⁽²⁾	MAX ⁽¹⁾	UNIT
Temperature accuracy ⁽³⁾	40°C to 150°C; V _{DD} = 2.2 V to 5.5 V	-2.7	±0.4	2.7	°C
	0°C to 40°C; V _{DD} = 2.4 V to 5.5 V	-2.7	±0.7	2.7	°C
	0°C to 70°C; V _{DD} = 3.0 V to 5.5 V		±0.3		°C
	-50°C to 0°C; V _{DD} = 3.0 V to 5.5 V	-2.7	±0.7	2.7	°C
	-50°C to 0°C; V _{DD} = 3.6 V to 5.5 V		±0.25		°C

- (1) Limits are specified to TI's AOQL (Average Outgoing Quality Level).
- (2) Typical values are at T_J = T_A = 25°C and represent most likely parametric norm.
- (3) Accuracy is defined as the error between the measured and reference output voltages, tabulated in the Transfer Table at the specified conditions of supply gain setting, voltage, and temperature (expressed in °C). Accuracy limits include line regulation within the specified conditions. Accuracy limits do not include load regulation; they assume no dc load.

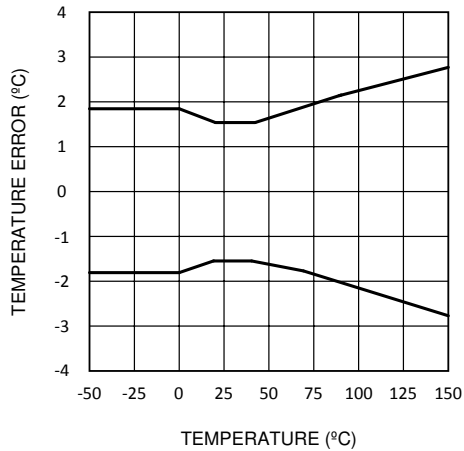
7.6 Electrical Characteristics

Unless otherwise noted, these specifications apply for +V_{DD} = 2.2 V to 5.5 V. MIN and MAX limits apply for T_A = T_J = T_{MIN} to T_{MAX}, unless otherwise noted; typical values apply for T_A = T_J = 25°C.

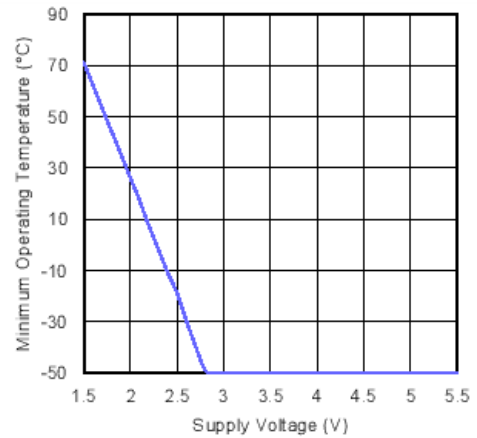
PARAMETER	TEST CONDITIONS	MIN ⁽¹⁾	TYP ⁽²⁾	MAX ⁽¹⁾	UNIT
Average sensor gain (output transfer function slope)	-30°C and 90°C used to calculate average sensor gain		-10.9		mV/°C
Load regulation ⁽³⁾	Source ≤ 50 μA, (V _{DD} - V _{OUT}) ≥ 200 mV	-1	-0.22		mV
	Sink ≤ 50 μA, V _{OUT} ≥ 200 mV		0.26	1	mV
Line regulation ⁽⁴⁾			200		μV/V
I _S Supply current	T _A = 30°C to 150°C, (V _{DD} - V _{OUT}) ≥ 100 mV		5.4	8.1	μA
	T _A = -50°C to 150°C, (V _{DD} - V _{OUT}) ≥ 100 mV		5.4	9	μA
C _L Output load capacitance			1100		pF
Power-on time ⁽⁵⁾	C _L = 0 pF to 1100 pF		0.7	1.9	ms
Output drive	T _A = T _J = 25°C	-50		50	μA

- (1) Limits are specific to TI's AOQL (Average Outgoing Quality Level).
- (2) Typical values are at T_J = T_A = 25°C and represent most likely parametric norm.
- (3) Source currents are flowing out of the LMT86-Q1. Sink currents are flowing into the LMT86-Q1.
- (4) Line regulation (DC) is calculated by subtracting the output voltage at the highest supply voltage from the output voltage at the lowest supply voltage. The typical DC line regulation specification does not include the output voltage shift discussed in [Output Voltage Shift](#).
- (5) Specified by design and characterization.

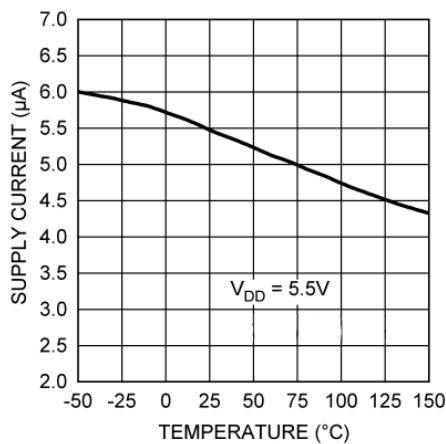
7.7 Typical Characteristics



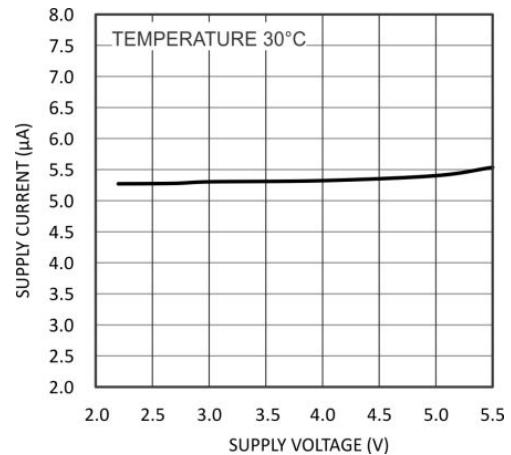
7-1. Temperature Error vs Temperature



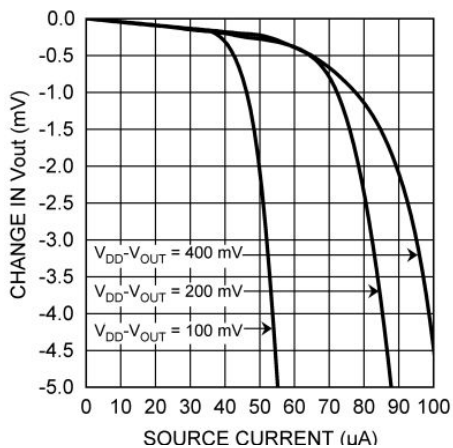
7-2. Minimum Operating Temperature vs Supply Voltage



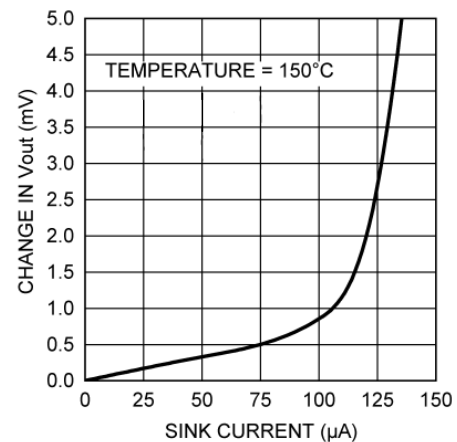
7-3. Supply Current vs Temperature



7-4. Supply Current vs Supply Voltage

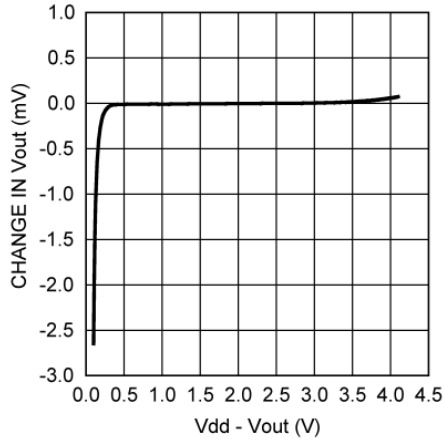


7-5. Load Regulation, Sourcing Current

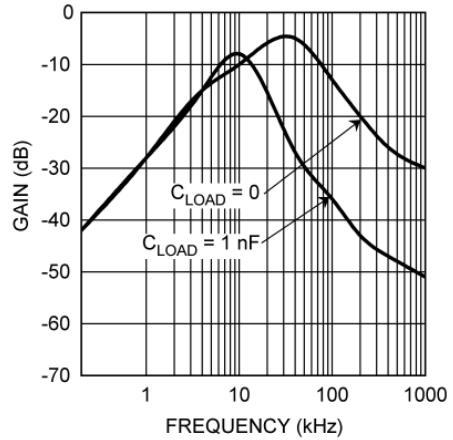


7-6. Load Regulation, Sinking Current

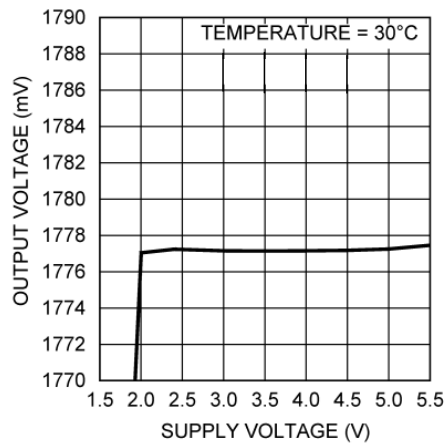
7.7 Typical Characteristics (continued)



7-7. Change in V_{OUT} vs Overhead Voltage



7-8. Supply-Noise Gain vs Frequency



7-9. Output Voltage vs Supply Voltage

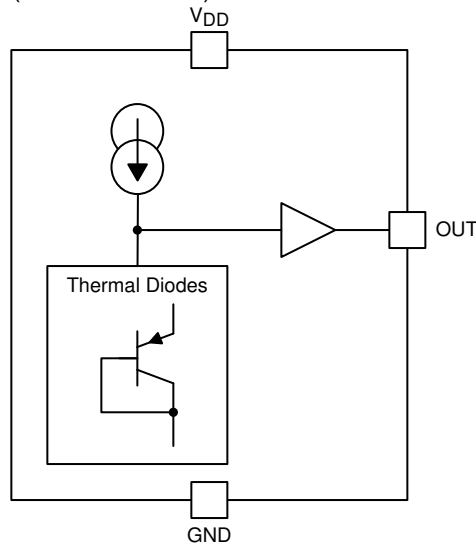
8 Detailed Description

8.1 Overview

The LMT86-Q1 is an analog output temperature sensor. The temperature-sensing element is comprised of a simple base emitter junction that is forward biased by a current source. The temperature-sensing element is then buffered by an amplifier and provided to the OUT pin. The amplifier has a simple push-pull output stage thus providing a low impedance output source.

8.2 Functional Block Diagram

Full-Range Celsius Temperature Sensor (–50°C to +150°C)



8.3 Feature Description

8.3.1 LMT86-Q1 Transfer Function

表 8-1 shows the output voltage of the LMT86-Q1 across the complete operating temperature range. This table is the reference from which the LMT86-Q1 accuracy specifications (listed in the *Accuracy Characteristics* table) are determined. This table can be used, for example, in a host processor look-up table. A file containing this data is available for download at [LMT86-Q1](#) product folder under *Tools and Software Models*.

表 8-1. LMT86-Q1 Transfer Table

TEMP (°C)	V _{OUT} (mV)	TEMP (°C)	V _{OUT} (mV)	TEMP (°C)	V _{OUT} (mV)	TEMP (°C)	V _{OUT} (mV)	TEMP (°C)	V _{OUT} (mV)
-50	2616	-10	2207	30	1777	70	1335	110	883
-49	2607	-9	2197	31	1766	71	1324	111	872
-48	2598	-8	2186	32	1756	72	1313	112	860
-47	2589	-7	2175	33	1745	73	1301	113	849
-46	2580	-6	2164	34	1734	74	1290	114	837
-45	2571	-5	2154	35	1723	75	1279	115	826
-44	2562	-4	2143	36	1712	76	1268	116	814
-43	2553	-3	2132	37	1701	77	1257	117	803
-42	2543	-2	2122	38	1690	78	1245	118	791
-41	2533	-1	2111	39	1679	79	1234	119	780
-40	2522	0	2100	40	1668	80	1223	120	769
-39	2512	1	2089	41	1657	81	1212	121	757
-38	2501	2	2079	42	1646	82	1201	122	745
-37	2491	3	2068	43	1635	83	1189	123	734
-36	2481	4	2057	44	1624	84	1178	124	722
-35	2470	5	2047	45	1613	85	1167	125	711

表 8-1. LMT86-Q1 Transfer Table (continued)

TEMP (°C)	V _{OUT} (mV)	TEMP (°C)	V _{OUT} (mV)	TEMP (°C)	V _{OUT} (mV)	TEMP (°C)	V _{OUT} (mV)	TEMP (°C)	V _{OUT} (mV)
-34	2460	6	2036	46	1602	86	1155	126	699
-33	2449	7	2025	47	1591	87	1144	127	688
-32	2439	8	2014	48	1580	88	1133	128	676
-31	2429	9	2004	49	1569	89	1122	129	665
-30	2418	10	1993	50	1558	90	1110	130	653
-29	2408	11	1982	51	1547	91	1099	131	642
-28	2397	12	1971	52	1536	92	1088	132	630
-27	2387	13	1961	53	1525	93	1076	133	618
-26	2376	14	1950	54	1514	94	1065	134	607
-25	2366	15	1939	55	1503	95	1054	135	595
-24	2355	16	1928	56	1492	96	1042	136	584
-23	2345	17	1918	57	1481	97	1031	137	572
-22	2334	18	1907	58	1470	98	1020	138	560
-21	2324	19	1896	59	1459	99	1008	139	549
-20	2313	20	1885	60	1448	100	997	140	537
-19	2302	21	1874	61	1436	101	986	141	525
-18	2292	22	1864	62	1425	102	974	142	514
-17	2281	23	1853	63	1414	103	963	143	502
-16	2271	24	1842	64	1403	104	951	144	490
-15	2260	25	1831	65	1391	105	940	145	479
-14	2250	26	1820	66	1380	106	929	146	467
-13	2239	27	1810	67	1369	107	917	147	455
-12	2228	28	1799	68	1358	108	906	148	443
-11	2218	29	1788	69	1346	109	895	149	432
								150	420

Although the LMT86-Q1 is very linear, its response does have a slight umbrella parabolic shape. 表 8-1 very accurately reflects this shape. The Transfer Table can be calculated by using the parabolic equation (式 1).

$$V_{TEMP} (mV) = 1777.3mV - \left[10.888 \frac{mV}{^{\circ}C} (T - 30^{\circ}C) \right] - \left[0.00347 \frac{mV}{^{\circ}C^2} (T - 30^{\circ}C)^2 \right] \quad (1)$$

The parabolic equation is an approximation of the transfer table and the accuracy of the equation degrades slightly at the temperature range extremes. 式 1 can be solved for T resulting in:

$$T = \frac{10.888 - \sqrt{(-10.888)^2 + 4 \times 0.00347 \times (1777.3 - V_{TEMP} (mV))}}{2 \times (-0.00347)} + 30 \quad (2)$$

For an even less accurate linear approximation, a line can easily be calculated over the desired temperature range from the table using the two-point equation (式 3):

$$V - V_1 = \left(\frac{V_2 - V_1}{T_2 - T_1} \right) \times (T - T_1) \quad (3)$$

where

- V is in mV,
- T is in °C,
- T₁ and V₁ are the coordinates of the lowest temperature,
- and T₂ and V₂ are the coordinates of the highest temperature.

For example, if the user wanted to resolve this equation, over a temperature range of 20°C to 50°C, they would proceed as follows:

$$V - 1885 \text{ mV} = \left(\frac{1558 \text{ mV} - 1885 \text{ mV}}{50^\circ\text{C} - 20^\circ\text{C}} \right) \times (T - 20^\circ\text{C}) \quad (4)$$

$$V - 1885 \text{ mV} = (-10.9 \text{ mV} / ^\circ\text{C}) \times (T - 20^\circ\text{C}) \quad (5)$$

$$V = (-10.9 \text{ mV} / ^\circ\text{C}) \times T + 2103 \text{ mV} \quad (6)$$

Using this method of linear approximation, the transfer function can be approximated for one or more temperature ranges of interest.

8.4 Device Functional Modes

8.4.1 Mounting and Thermal Conductivity

The LMT86-Q1 can be applied easily in the same way as other integrated-circuit temperature sensors. It can be glued or cemented to a surface.

To ensure good thermal conductivity, the backside of the LMT86-Q1 die is directly attached to the GND pin. The temperatures of the lands and traces to the other leads of the LMT86-Q1 will also affect the temperature reading.

Alternatively, the LMT86-Q1 can be mounted inside a sealed-end metal tube, and can then be dipped into a bath or screwed into a threaded hole in a tank. As with any IC, the LMT86-Q1 and accompanying wiring and circuits must be kept insulated and dry, to avoid leakage and corrosion. This is especially true if the circuit may operate at cold temperatures where condensation can occur. If moisture creates a short circuit from the output to ground or V_{DD} , the output from the LMT86-Q1 will not be correct. Printed-circuit coatings are often used to ensure that moisture cannot corrode the leads or circuit traces.

The thermal resistance junction to ambient ($R_{\theta JA}$ or θ_{JA}) is the parameter used to calculate the rise of a device junction temperature due to its power dissipation. Use [式 7](#) to calculate the rise in the LMT86-Q1 die temperature:

$$T_J = T_A + \theta_{JA} [(V_{DD} I_S) + (V_{DD} - V_O) I_L] \quad (7)$$

where

- T_A is the ambient temperature,
- I_S is the supply current,
- I_L is the load current on the output,
- and V_O is the output voltage.

For example, in an application where $T_A = 30^\circ\text{C}$, $V_{DD} = 5 \text{ V}$, $I_S = 5.4 \mu\text{A}$, $V_O = 1777 \text{ mV}$ junction temp 30.014°C self-heating error of 0.014°C . Because the junction temperature of the LMT86-Q1 is the actual temperature being measured, take care to minimize the load current that the LMT86-Q1 is required to drive. The *Thermal Information* table shows the thermal resistance of the LMT86-Q1.

8.4.2 Output Noise Considerations

A push-pull output gives the LMT86-Q1 the ability to sink and source significant current. This is beneficial when, for example, driving dynamic loads like an input stage on an analog-to-digital converter (ADC). In these applications the source current is required to quickly charge the input capacitor of the ADC. The LMT86-Q1 is ideal for this and other applications which require strong source or sink current.

The LMT86-Q1 supply-noise gain (the ratio of the AC signal on V_{OUT} to the AC signal on V_{DD}) was measured during bench tests. [图 7-8](#) shows the typical attenuation found in the [Typical Characteristics](#) section. A load capacitor on the output can help to filter noise.

For operation in very noisy environments, some bypass capacitance should be present on the supply within approximately 5 centimeters of the LMT86-Q1.

8.4.3 Capacitive Loads

The LMT86-Q1 handles capacitive loading well. In an extremely noisy environment, or when driving a switched sampling input on an ADC, it may be necessary to add some filtering to minimize noise coupling. Without any precautions, [Figure 8-1](#) shows how the LMT86-Q1 can drive a capacitive load less than or equal to 1100 pF. For capacitive loads greater than 1100 pF, [Figure 8-2](#) shows how a series resistor may be required on the output.

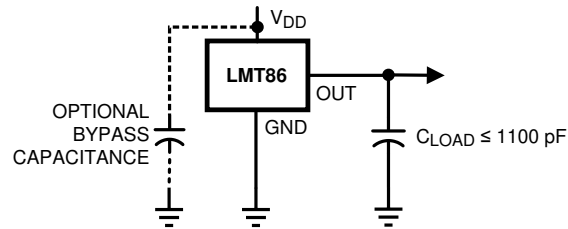


Figure 8-1. LMT86-Q1 No Decoupling Required for Capacitive Loads Less Than 1100 pF

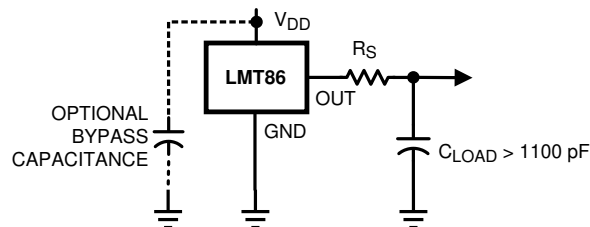


Figure 8-2. LMT86-Q1 With Series Resistor for Capacitive Loading Greater Than 1100 pF

Table 8-2. Recommended Series Resistor Values

C_{LOAD}	MINIMUM R_S
1.1 nF to 99 nF	3 k Ω
100 nF to 999 nF	1.5 k Ω
1 μ F	800 Ω

8.4.4 Output Voltage Shift

The LMT86-Q1 device is very linear over temperature and supply voltage range. Due to the intrinsic behavior of an NMOS/PMOS rail-to-rail buffer, a slight shift in the output can occur when the supply voltage is ramped over the operating range of the device. The location of the shift is determined by the relative levels of V_{DD} and V_{OUT} . The shift typically occurs when $V_{DD} - V_{OUT} = 1$ V.

This slight shift (a few millivolts) takes place over a wide change (approximately 200 mV) in V_{DD} or V_{OUT} . Because the shift takes place over a wide temperature change of 5°C to 20°C, V_{OUT} is always monotonic. The accuracy specifications in the *Accuracy Characteristics* table already include this possible shift.

9 Application and Implementation

注

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9.1 Application Information

The LMT86-Q1 features make it suitable for many general temperature-sensing applications. It can operate down to 2.2-V supply with 5.4- μ A power consumption, making it ideal for battery-powered devices.

9.2 Typical Applications

9.2.1 Connection to an ADC

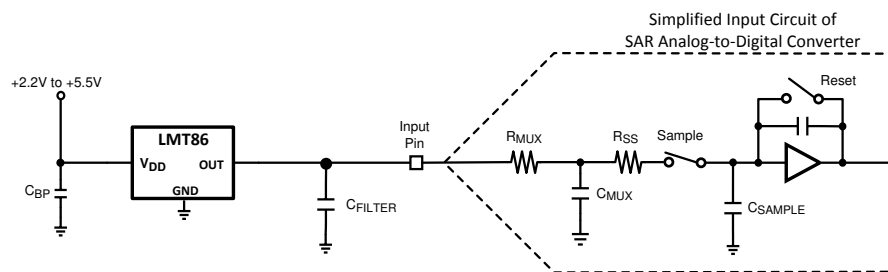


図 9-1. Suggested Connection to a Sampling Analog-to-Digital Converter Input Stage

9.2.1.1 Design Requirements

Most CMOS ADCs found in microcontrollers and ASICs have a sampled data comparator input structure. When the ADC charges the sampling cap, it requires instantaneous charge from the output of the analog source such as the LMT86 temperature sensor and many op amps. This requirement is easily accommodated by the addition of a capacitor, C_{FILTER} .

9.2.1.2 Detailed Design Procedure

The size of C_{FILTER} depends on the size of the sampling capacitor and the sampling frequency. Because not all ADCs have identical input stages, the charge requirements will vary. This general ADC application is shown as an example only.

9.2.1.3 Application Curve

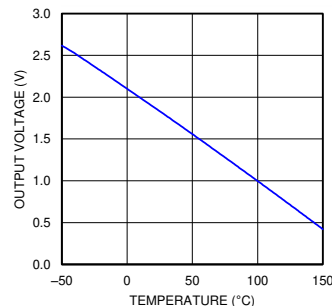
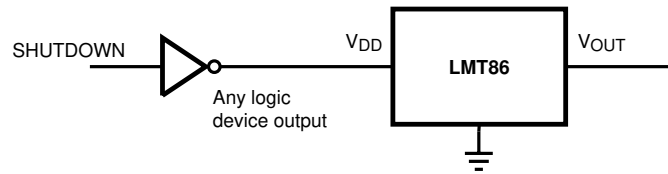


図 9-2. Analog Output Transfer Function

9.2.2 Conserving Power Dissipation With Shutdown



9-3. Conserving Power Dissipation With Shutdown

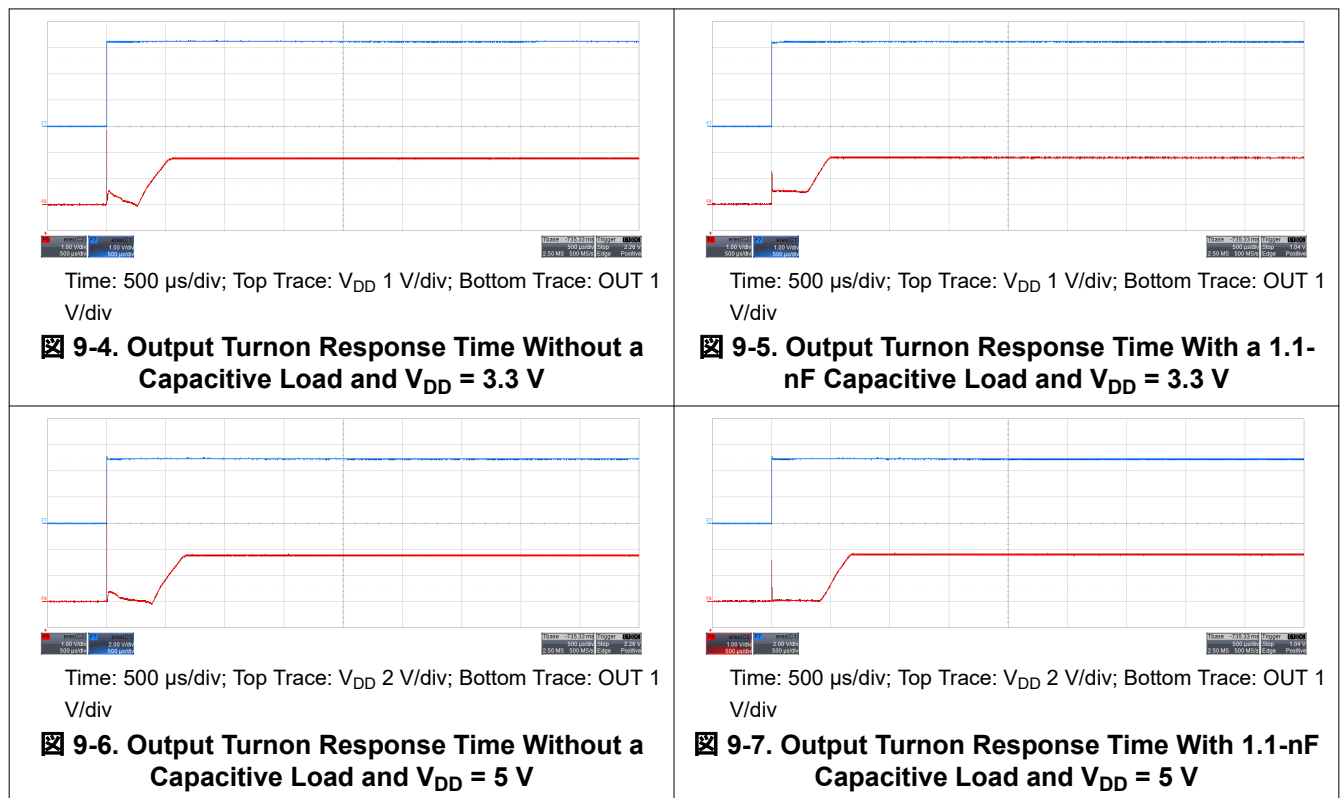
9.2.2.1 Design Requirements

Because the power consumption of the LMT86-Q1 is less than 9 μA , it can simply be powered directly from any logic gate output and therefore not require a specific shutdown pin. The device can even be powered directly from a microcontroller GPIO. In this way, it can easily be turned off for cases such as battery-powered systems where power savings are critical.

9.2.2.2 Detailed Design Procedure

Simply connect the V_{DD} pin of the LMT86-Q1 directly to the logic shutdown signal from a microcontroller.

9.2.2.3 Application Curves



10 Power Supply Recommendations

The low supply current and supply range (2.2 V to 5.5 V) of the LMT86-Q1 allow the device to easily be powered from many sources. Power supply bypassing is optional and is mainly dependent on the noise on the power supply used. In noisy systems, it may be necessary to add bypass capacitors to lower the noise that is coupled to the output of the LMT86-Q1.

11 Layout

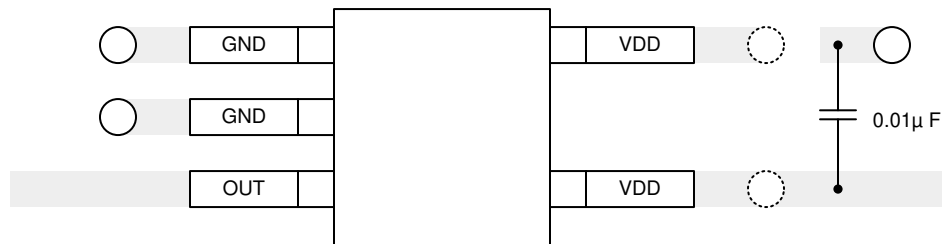
11.1 Layout Guidelines

The LMT86-Q1 is simple to layout. If a power-supply bypass capacitor is used, the [Layout Example](#) shows how to connect the capacitor to the device.

11.2 Layout Example

○ VIA to ground plane

○ VIA to power plane



11-1. SC70 Package Recommended Layout

12 Device and Documentation Support

12.1 Receiving Notification of Documentation Updates

To receive notification of documentation updates, navigate to the device product folder on [ti.com](https://www.ti.com). Click on *Subscribe to updates* to register and receive a weekly digest of any product information that has changed. For change details, review the revision history included in any revised document.

12.2 サポート・リソース

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12.4 Electrostatic Discharge Caution



This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

12.5 Glossary

[TI Glossary](#) This glossary lists and explains terms, acronyms, and definitions.

13 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead finish/ Ball material (6)	MSL Peak Temp (3)	Op Temp (°C)	Device Marking (4/5)	Samples
LMT86QDCKRQ1	ACTIVE	SC70	DCK	5	3000	RoHS & Green	SN	Level-1-260C-UNLIM	-50 to 150	BTA	Samples
LMT86QDCKTQ1	OBSOLETE	SC70	DCK	5		TBD	Call TI	Call TI	-50 to 150	BTA	

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) **RoHS:** TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (Cl) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

(3) MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

(4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

(5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

(6) Lead finish/Ball material - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

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OTHER QUALIFIED VERSIONS OF LMT86-Q1 :

- Catalog : [LMT86](#)

NOTE: Qualified Version Definitions:

- Catalog - TI's standard catalog product

TAPE AND REEL INFORMATION

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE


*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
LMT86QDCKRQ1	SC70	DCK	5	3000	178.0	8.4	2.25	2.45	1.2	4.0	8.0	Q3

TAPE AND REEL BOX DIMENSIONS


*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
LMT86QDCKRQ1	SC70	DCK	5	3000	208.0	191.0	35.0

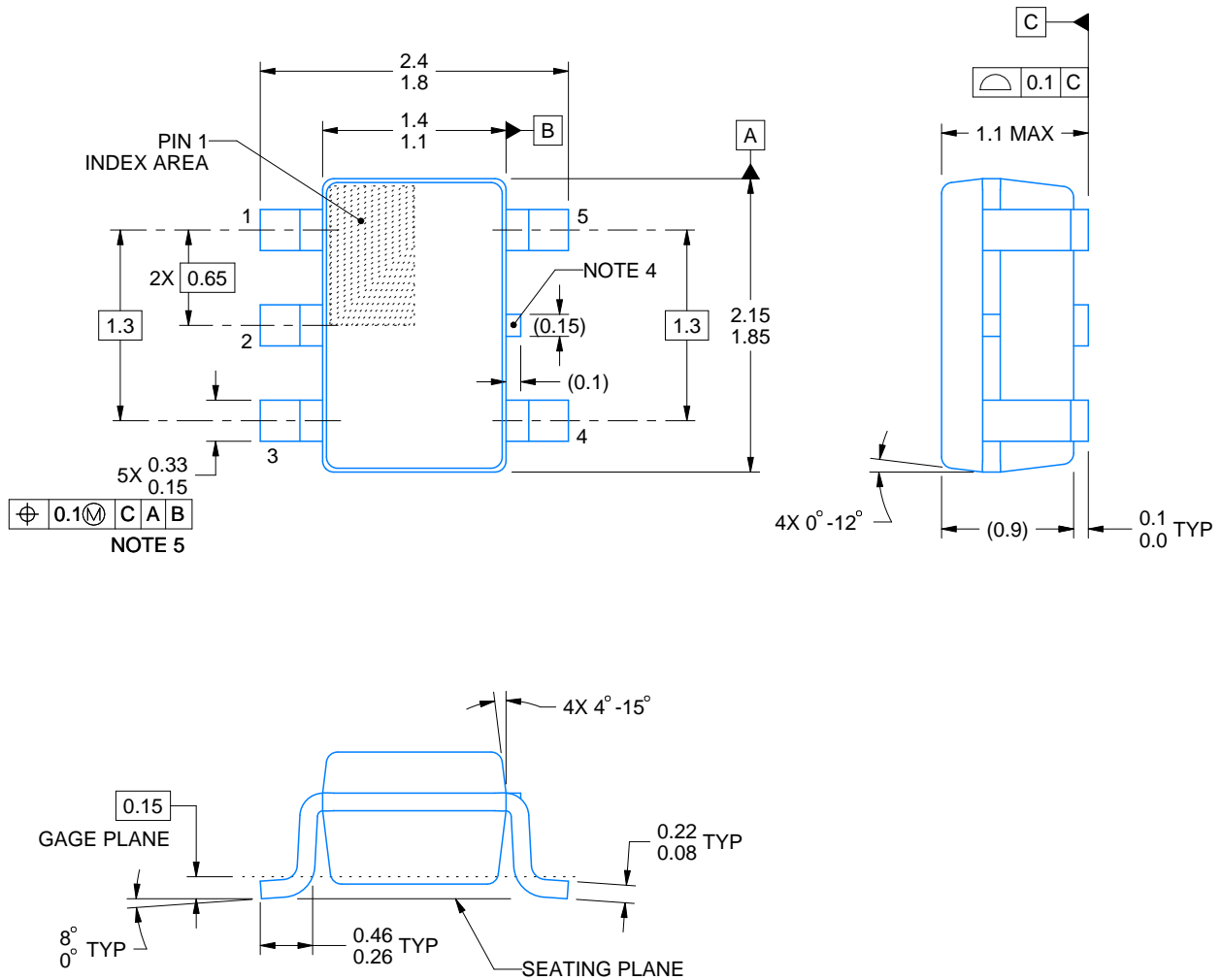
DCK0005A



PACKAGE OUTLINE

SOT - 1.1 max height

SMALL OUTLINE TRANSISTOR



4214834/G 11/2024

NOTES:

1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. Reference JEDEC MO-203.
4. Support pin may differ or may not be present.
5. Lead width does not comply with JEDEC.
6. Body dimensions do not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.25mm per side

EXAMPLE BOARD LAYOUT

DCK0005A

SOT - 1.1 max height

SMALL OUTLINE TRANSISTOR



LAND PATTERN EXAMPLE
EXPOSED METAL SHOWN
SCALE:18X



SOLDER MASK DETAILS

4214834/G 11/2024

NOTES: (continued)

- 7. Publication IPC-7351 may have alternate designs.
- 8. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

EXAMPLE STENCIL DESIGN

DCK0005A

SOT - 1.1 max height

SMALL OUTLINE TRANSISTOR



SOLDER PASTE EXAMPLE
BASED ON 0.125 THICK STENCIL
SCALE:18X

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NOTES: (continued)

9. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
10. Board assembly site may have different recommendations for stencil design.

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